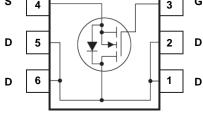


SuperSOT[™] -6



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units
V _{DS}	Drain to Source Voltage			30	V
V _{GS}	Gate to Source Voltage		(Note 3)	±20	V
	Drain Current -Continuous (Package limited) T _C = 25 °C			8.0	
I _D	-Continuous	T _A = 25 °C	(Note 1a)	8.0	А
	-Pulsed			32	
P _D	Power Dissipation (Note		(Note 1a)	1.6	14/
	Power Dissipation (No		(Note 1b)	0.8	W
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	30	°C/W
R_{\thetaJA}	Thermal Resistance, Junction to Ambient (Note 1	a) 78	C/vv

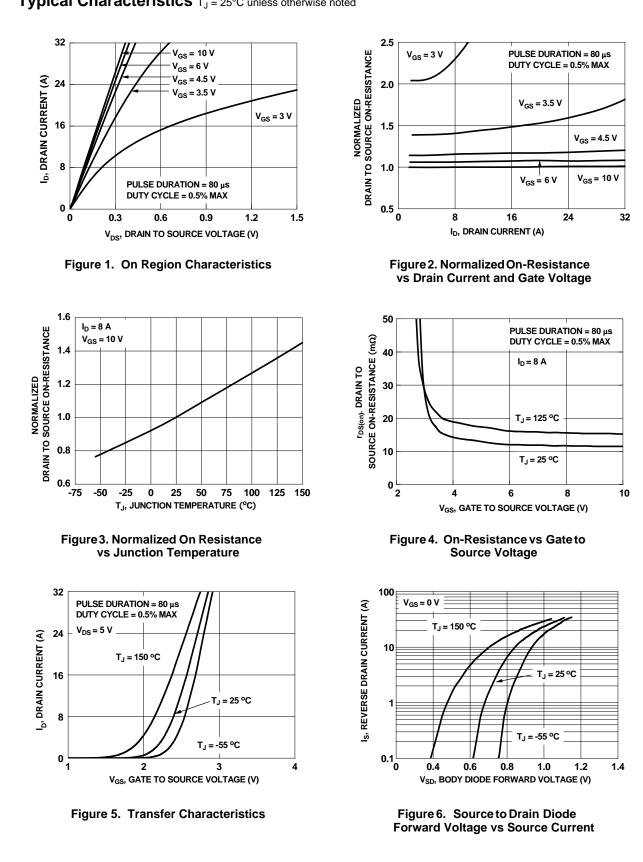
Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
.888	FDC8878	SSOT-6	7 " 8 mm		3000 units

FDC8878
N-Channel
PowerTrench [®]
MOSFET

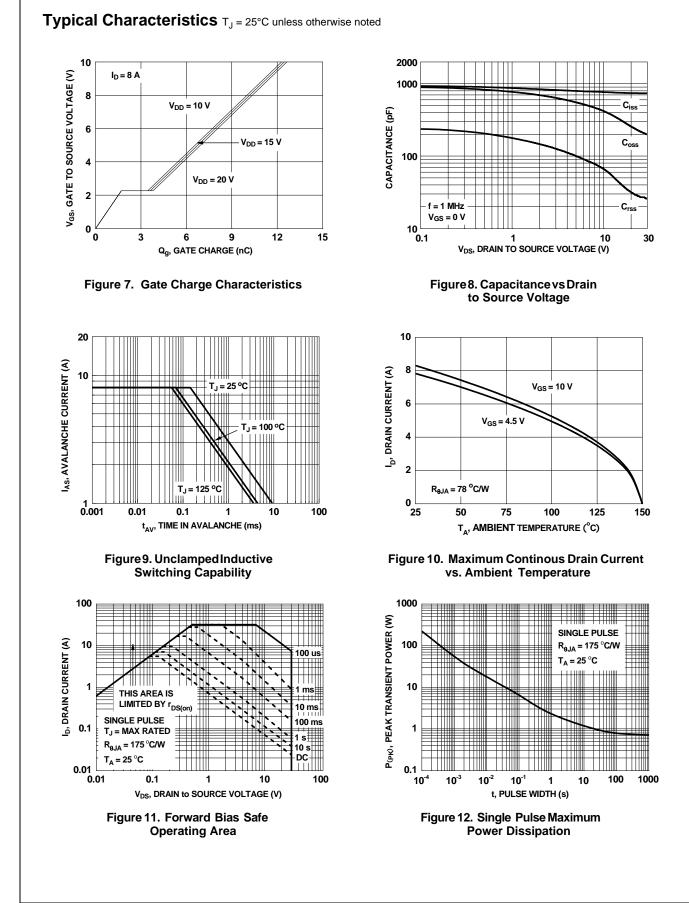
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Off Chara	cteristics					
BV _{DSS}	Drain to Source Breakdown Voltage	I _D = 250 μA, V _{GS} = 0 V	30			V
$\frac{\Delta BV_{DSS}}{\Delta T_J}$	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		13		mV/°0
IDSS	Zero Gate Voltage Drain Current	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$			1	μA
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 \text{ V}, V_{DS} = 0 \text{ V}$			100	nA
On Chara	cteristics					
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.2	1.6	3.0	V
$\Delta V_{GS(th)}$	Gate to Source Threshold Voltage				0.0	
ΔT_J	Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		-5		mV/°0
		$V_{GS} = 10 \text{ V}, \ \text{I}_{D} = 8.0 \text{ A}$		12	16	
r _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 4.5 \text{ V}, \ I_D = 7.5 \text{ A}$		14	18	mΩ
		$V_{GS} = 10 \text{ V}, \ \text{I}_{D} = 8.0 \text{ A}, \text{T}_{J} = 125 ^{\circ}\text{C}$		16	21	
9 _{FS}	Forward Transconductance	$V_{DD} = 5 V, I_{D} = 8.0 A$		43		S
Dynamic (Characteristics					
C _{iss}	Input Capacitance			782	1040	pF
C _{oss}	Output Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		318	425	pF
C _{rss}	Reverse Transfer Capacitance			40	60	pF
Rg	Gate Resistance			1.2		Ω
	Characteristics			6	12	ns
t _{d(on)} t	Rise Time			2	12	ns
t _r	Turn-Off Delay Time	$V_{DD} = 15 \text{ V, } I_D = 8 \text{ A,}$ $V_{GS} = 10 \text{ V, } R_{GEN} = 6 \Omega$		17	30	ns
t _{d(off)}	Fall Time			2	10	ns
t _f	Total Gate Charge	V _{GS} = 0 V to 10 V		13	18	nC
Q _{g(TOT)}	Total Gate Charge			6	9	nC
Q _{gs}	Total Gate Charge	$V_{GS} = 0 V \text{ to } 4.5 V$ $V_{DD} = 15 V$ $I_D = 8 A$		1.7	5	nC
Q _{gd}	Gate to Drain "Miller" Charge			2.0		nC
×						
	Irce Diode Characteristics Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_{S} = 8.0 A$ (Note 2)		0.8	1.2	V
V _{SD}	Reverse Recovery Time	$V_{GS} = 0.0$, $I_{S} = 8.0$ A (Note 2)		22	35	
Q _{rr}	Reverse Recovery Charge	I _F = 8.0 A, di/dt = 100 A/μs		7	- 35 - 14	ns nC
NOTES: I. R _{θJA} is the sun	n of the junction-to-case and case-to-ambient thermal resis d by design while R _{6CA} is determined by the user's board d		as the solde			
	a. 78 °C/W when mour a 1 in ² pad of 2 oz		C/W when m mum pad of	nounted on 2 oz coppe	ər	

Pulse Test: Pulse Width < 300 μs, Duty cycle < 2.0 %.
 As an N-ch device, the negative Vgs rating is for low duty cycle pulse occurrence only. No continuous rating is implied.

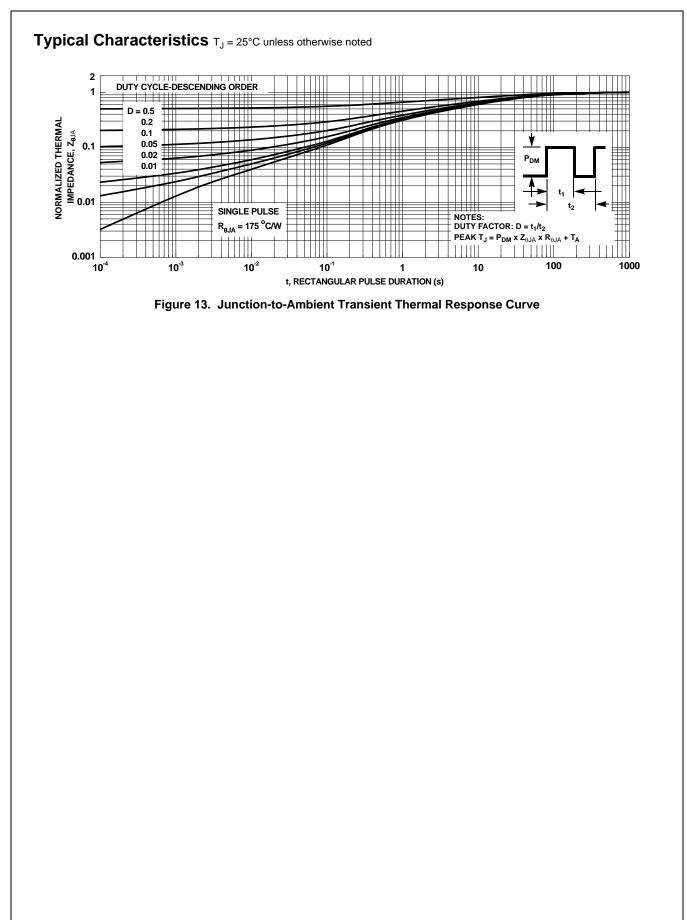


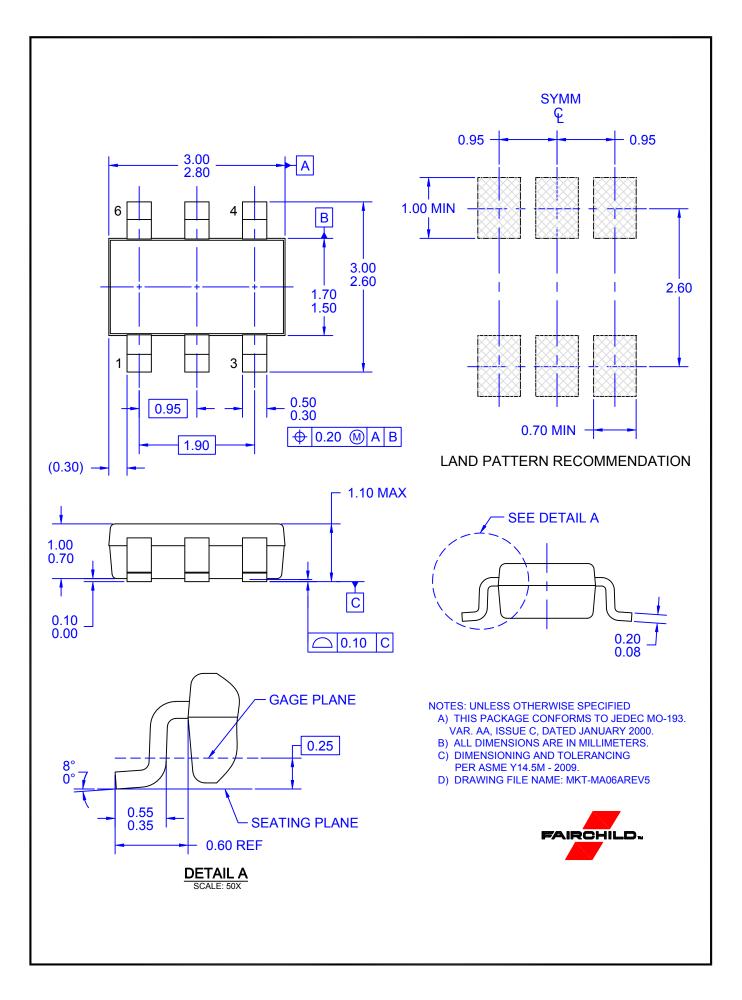
Typical Characteristics T_J = 25°C unless otherwise noted





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